Number 1	51	<b>,</b>		Time stamp
1	51			1
	91	(gate or electrode) and silicide and	USPAT;	2004/11/17
		polysilicon and (re adj oxidizing)	US-PGPUB	08:39
2	40	((gate or electrode) and silicide and	USPAT;	2004/11/17
		<pre>polysilicon and (re adj oxidizing)) and @ad&lt;20021031</pre>	US-PGPUB	08:40
3	3	(gate or electrode) and silicide and	EPO; JPO;	2004/11/17
		polysilicon and (re adj oxidizing)	DERWENT; IBM TDB	07:59
4	4047	(gate or electrode) and silicide and	USPĀT;	2004/11/17
		polysilicon and (oxidizing)	US-PGPUB	08:39
5	1644	(gate or electrode) and silicide and	USPAT;	2004/11/17
		<pre>polysilicon and (oxidizing with (gate or electrode))</pre>	US-PGPUB	08:58
6	801	((gate or electrode) and silicide and	USPAT;	2004/11/17
		<pre>polysilicon and (oxidizing with (gate or electrode))) and (oxidizing with substrate)</pre>	US-PGPUB	08:40
7	630	(((gate or electrode) and silicide and	USPAT;	2004/11/17
		polysilicon and (oxidizing with (gate or electrode))) and (oxidizing with substrate)) and @ad<20021031	US-PGPUB	08:43
8	274	(((gate or electrode) and silicide and	USPAT;	2004/11/17
	•	polysilicon and (oxidizing with (gate or electrode))) and (oxidizing with substrate)) and @ad<20021031) and oxygen and (inert or argon or nitrogen or	US-PGPUB	08:58
		helium)		
9	39	(gate or electrode) and silicide and	EPO; JPO;	2004/11/17
		<pre>polysilicon and (oxidizing with (gate or electrode))</pre>	DERWENT; IBM TDB	08:58
10	2	((gate or electrode) and silicide and	EPO; JPO;	2004/11/17
	-	polysilicon and (oxidizing with (gate or	DERWENT;	08:58
		electrode))) and oxygen and (inert or	IBM TDB	
		argon or nitrogen or helium)		

L	Hits	Search Text	DB	Time stamp
Number				
1	4173	438/299,303,595,655,656,660,663,682.ccls.	USPAT;	2004/11/17
			US-PGPUB	10:29
2	1987	438/299,303,595,655,656,660,663,682.ccls.	USPAT;	2004/11/17
		and silicide and polysilicon	US-PGPUB	10:29
3	1891	(438/299,303,595,655,656,660,663,682.ccls.	USPAT;	2004/11/17
		and silicide and polysilicon) and (gate	US-PGPUB	10:30
		or electrode)		
4	703	((438/299,303,595,655,656,660,663,682.ccls	.USPAT;	2004/11/17
		and silicide and polysilicon) and (gate	US-PGPUB	10:30
		or electrode)) and oxygen		
5	651	(((438/299,303,595,655,656,660,663,682.ccl	SUSPAT;	2004/11/17
		and silicide and polysilicon) and (gate	US-PGPUB	10:31
		or electrode)) and oxygen) and		